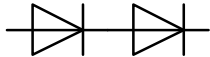


N**Datenblatt / Data sheet****Netz-Dioden-Modul
Rectifier Diode Module****DD231N**Infineon Technologies Bipolar
GmbH & Co. KG**DD231N****Elektrische Eigenschaften / Electrical properties**

Höchstzulässige Werte / Maximum rated values

Periodische Spitzensperrspannung repetitive peak reverse voltages	$T_{vj} = -40^{\circ}\text{C} \dots T_{vj\text{ max}}$	V_{RRM}	2000 2400	2200 2600	V V
Stoßspitzensperrspannung non-repetitive peak reverse voltage	$T_{vj} = +25^{\circ}\text{C} \dots T_{vj\text{ max}}$	V_{RSM}	2100 2500	2300 2700	V V
Durchlaßstrom-Grenzeffektivwert maximum RMS on-state current		I_{FRMSM}		410	A
Dauergrenzstrom average on-state current	$T_C = 100^{\circ}\text{C}$ $T_C = 91^{\circ}\text{C}$	I_{FAVM}		231 261	A A
Stoßstrom-Grenzwert surge current	$T_{vj} = 25^{\circ}\text{C}, t_P = 10\text{ ms}$ $T_{vj} = T_{vj\text{ max}}, t_P = 10\text{ ms}$	I_{FSM}		7.500 6.400	A A
Grenzlastintegral I^2t -value	$T_{vj} = 25^{\circ}\text{C}, t_P = 10\text{ ms}$ $T_{vj} = T_{vj\text{ max}}, t_P = 10\text{ ms}$	I^2t		281.000 205.000	A ² s A ² s

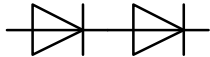
Charakteristische Werte / Characteristic values


Durchlaßspannung on-state voltage	$T_{vj} = T_{vj\text{ max}}, I_F = 800\text{ A}$	V_F	max.	1,55	V
Schleusenspannung threshold voltage	$T_{vj} = T_{vj\text{ max}}$	$V_{(TO)}$		0,8	V
Ersatzwiderstand slope resistance	$T_{vj} = T_{vj\text{ max}}$	r_T		0,84	mΩ
Sperrstrom reverse current	$T_{vj} = T_{vj\text{ max}}, V_R = V_{RRM}$	i_R	max.	25	mA
Isolations-Prüfspannung insulation test voltage	RMS, $f = 50\text{ Hz}, t = 1\text{ sec}$ RMS, $f = 50\text{ Hz}, t = 1\text{ min}$	V_{ISOL}		3,6 3,0	kV kV

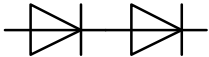
Thermische Eigenschaften / Thermal properties

Innerer Wärmewiderstand thermal resistance, junction to case	pro Modul / per Module, $\Theta = 180^{\circ}\text{ sin}$ pro Zweig / per arm, $\Theta = 180^{\circ}\text{ sin}$ pro Modul / per Module, DC pro Zweig / per arm, DC	R_{thJC}	max.	0,085 0,170 0,082 0,164	°C/W °C/W °C/W °C/W
Übergangs-Wärmewiderstand thermal resistance, case to heatsink	pro Modul / per Module pro Zweig / per arm	R_{thCH}	max.	0,02 0,04	°C/W °C/W
Höchstzulässige Sperrschichttemperatur maximum junction temperature		$T_{vj\text{ max}}$		150	°C
Betriebstemperatur operating temperature		$T_{c\text{ op}}$		- 40...+150	°C
Lagertemperatur storage temperature		T_{stg}		- 40...+150	°C

prepared by:	M.Stelte	date of publication:	2011-03-01
approved by:	M. Leifeld	revision:	3.0

N**Datenblatt / Data sheet**
Netz-Dioden-Modul
Rectifier Diode Module
DD231N
 Infineon Technologies Bipolar
 GmbH & Co. KG
Mechanische Eigenschaften / Mechanical properties

Gehäuse, siehe Anlage case, see annex			Seite 3 page 3	
Si-Element mit Druckkontakt Si-pellet with pressure contact				
Innere Isolation internal insulation			AIN	
Anzugsdrehmoment für mechanische Anschlüsse mounting torque	Toleranz $\pm 15\%$	M1	5	Nm
Anzugsdrehmoment für elektrische Anschlüsse terminal connection torque	Toleranz $\pm 10\%$	M2	12	Nm
Gewicht weight		G	typ. 800	g
Kriechstrecke creepage distance			17	mm
Schwingfestigkeit vibration resistance	f = 50 Hz		50	m/s ²
	file-No.		E 83336	

N

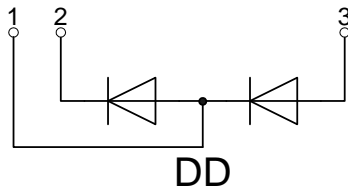
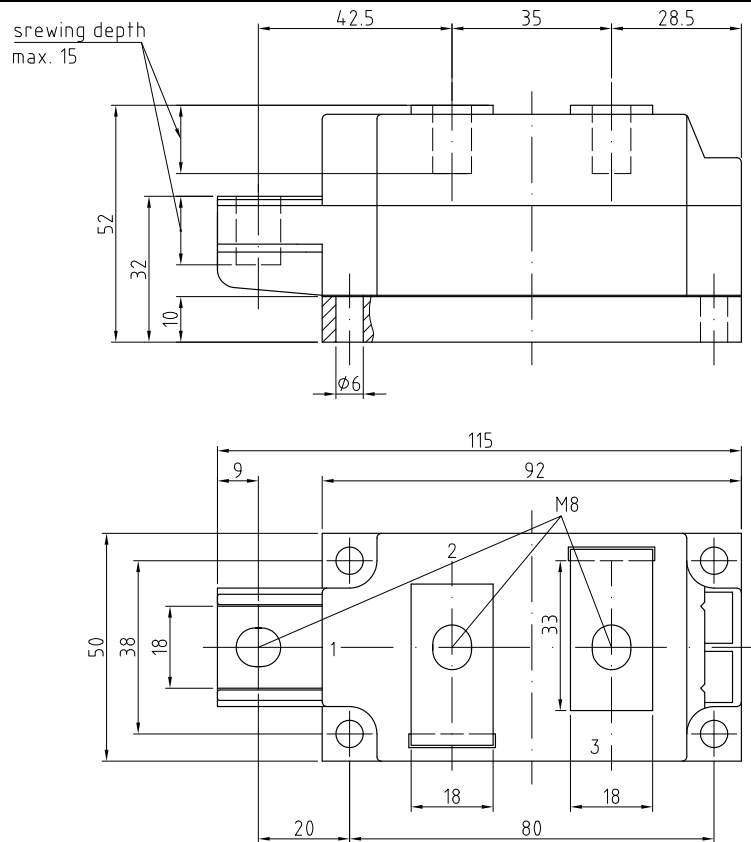
Datenblatt / Data sheet

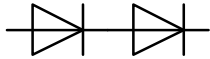


Netz-Dioden-Modul
Rectifier Diode Module

DD231N

Infineon Technologies Bipolar
GmbH & Co. KG

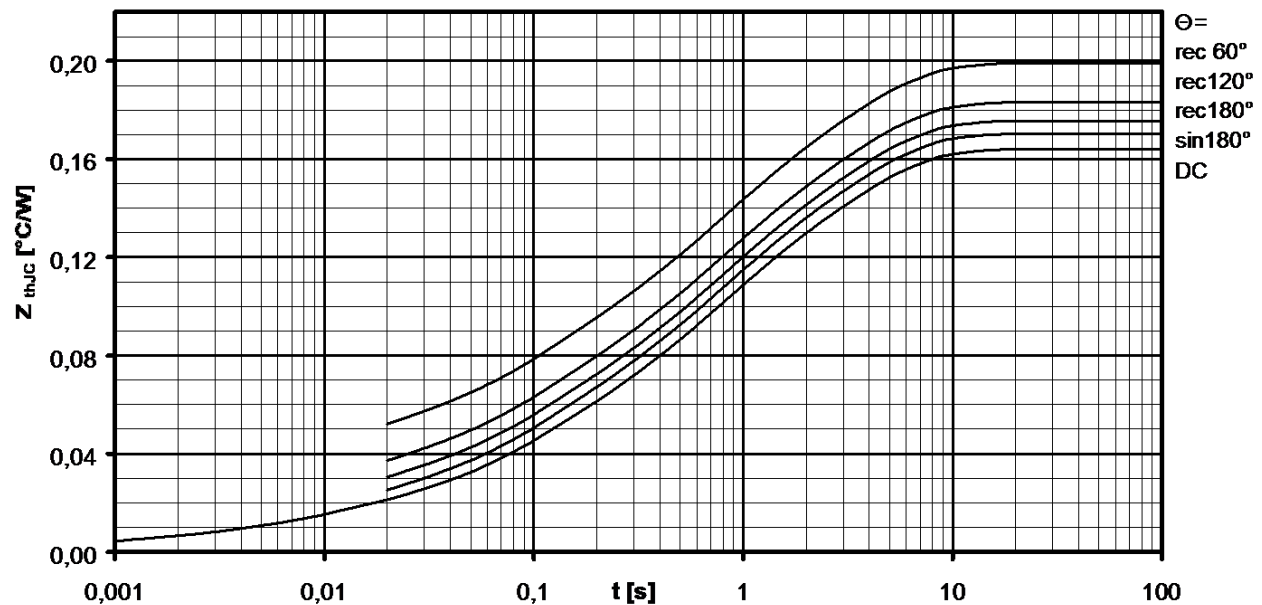



Analytische Elemente des transienten Wärmewiderstandes Z_{thJC} für DC
Analytical elements of transient thermal impedance Z_{thJC} for DC

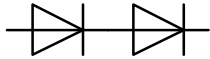
Pos. n	1	2	3	4	5	6	7
R_{thn} [°C/W]	0,0039	0,0097	0,0291	0,0552	0,0661		
T_n [s]	0,0008	0,008	0,085	0,54	2,85		

Analytische Funktion / Analytical function:

$$Z_{thJC} = \sum_{n=1}^{n_{max}} R_{thn} \left(1 - e^{-\frac{t}{\tau_n}} \right)$$


 Transienter innerer Wärmewiderstand je Zweig / Transient thermal impedance per arm $Z_{thJC} = f(t)$

 Parameter: Stromflußwinkel Θ / Current conduction angle Θ

N**Datenblatt / Data sheet**
Netz-Dioden-Modul
Rectifier Diode Module
DD231N
 Infineon Technologies Bipolar
 GmbH & Co. KG

 Natürliche Kühlung / Natural cooling
 3 Module pro Kühler / 3 modules per heatsink
 Kühler / Heatsink type: KM17 (60W)

Analytische Elemente des transienten Wärmewiderstandes Z_{thCA}
Analytical elements of transient thermal impedance Z_{thCA}

Pos. n	1	2	3	4	5	6	7
R_{thn} [°C/W]	0,0205	0,07905	1,535				
T_n [s]	2,04	36,4	1340				

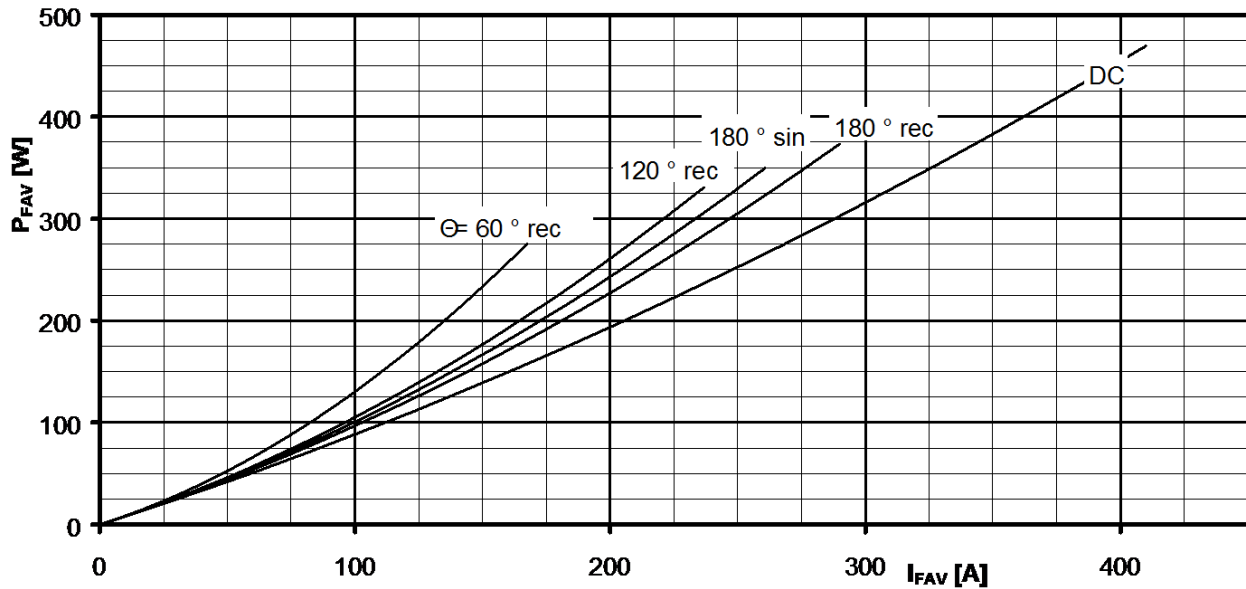
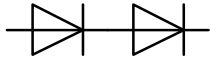
 Verstärkte Kühlung / Forced cooling
 3 Module pro Kühler / 3 modules per heatsink
 Kühler / Heatsink type: KM17 (Papst 4650)

Analytische Elemente des transienten Wärmewiderstandes Z_{thCA}
Analytical elements of transient thermal impedance Z_{thCA}

Pos. n	1	2	3	4	5	6	7
R_{thn} [°C/W]	0,015	0,08	0,475				
T_n [s]	4,11	40,4	458				

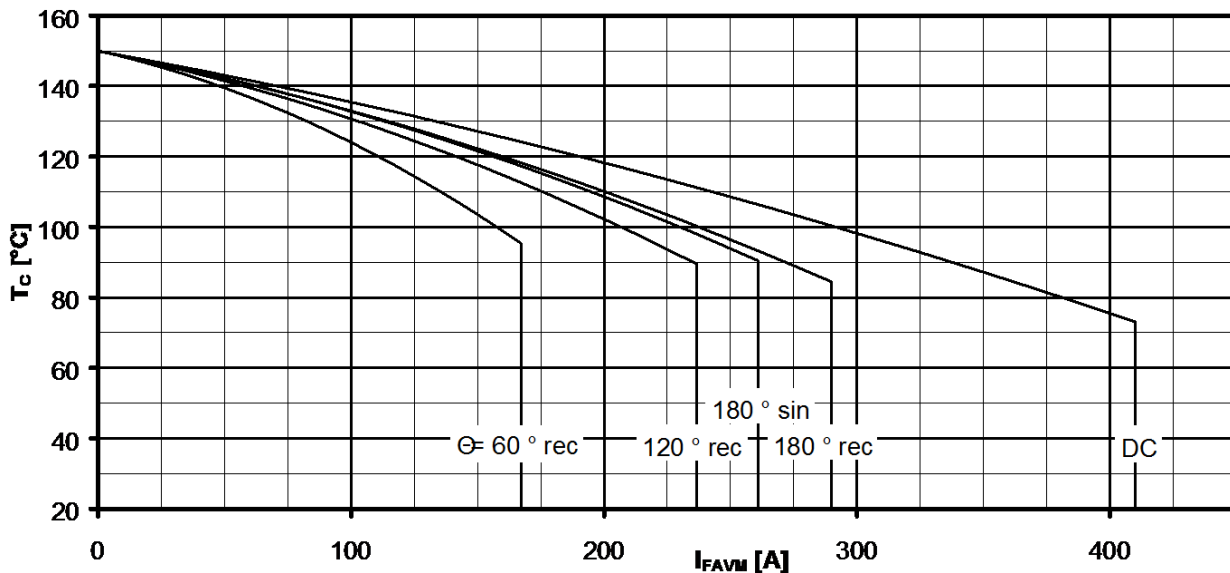
Analytische Funktion / Analytical function:

$$Z_{thCA} = \sum_{n=1}^{n_{max}} R_{thn} \left(1 - e^{-\frac{t}{\tau_n}} \right)$$



Durchlassverlustleistung je Zweig / On-state power loss per arm $P_{FAV} = f(I_{FAV})$

Parameter: Stromflußwinkel / Current conduction angle Θ

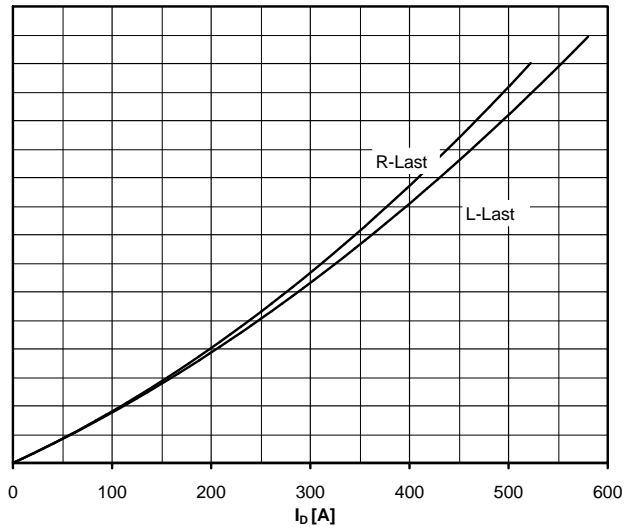
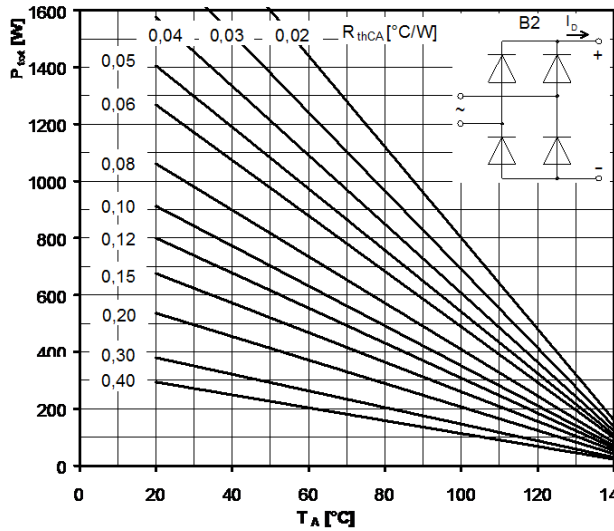
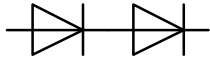


Höchstzulässige Gehäusetemperatur / Maximum allowable case temperature $T_C = f(I_{FAVM})$

Strombelastung je Zweig / Current load per arm

Berechnungsgrundlage P_{TAV} (Schaltverluste gesondert berücksichtigen)
Calculation base P_{TAV} (switching losses should be considered separately)

Parameter: Stromflußwinkel Θ / Current conduction angle Θ



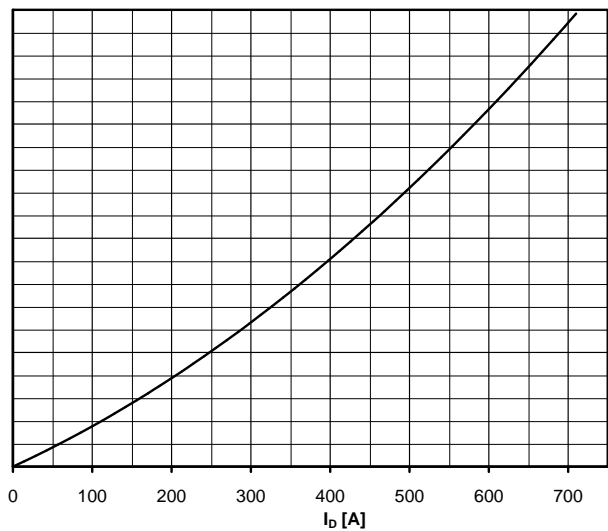
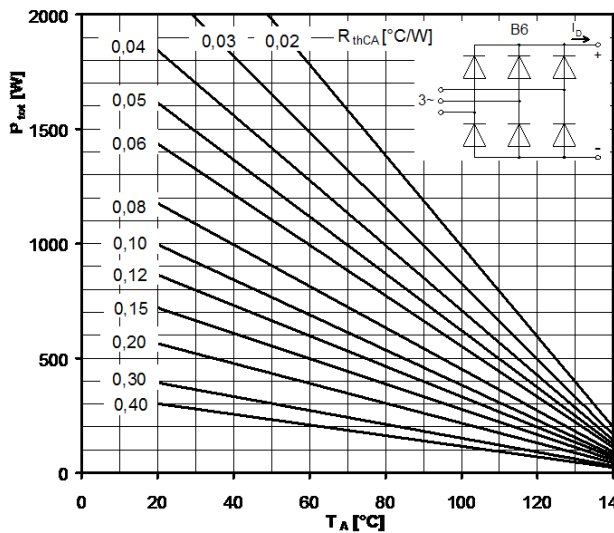
Höchstzulässiger Ausgangsstrom / Maximum rated output current I_D

B2- Zweipuls-Brückenschaltung / Two-pulse bridge circuit

Gesamtverlustleistung der Schaltung / Total power dissipation at circuit P_{tot}

Parameter:

Wärmewiderstand zwischen den Gehäusen und Umgebung / Thermal resistance cases to ambient R_{thCA}



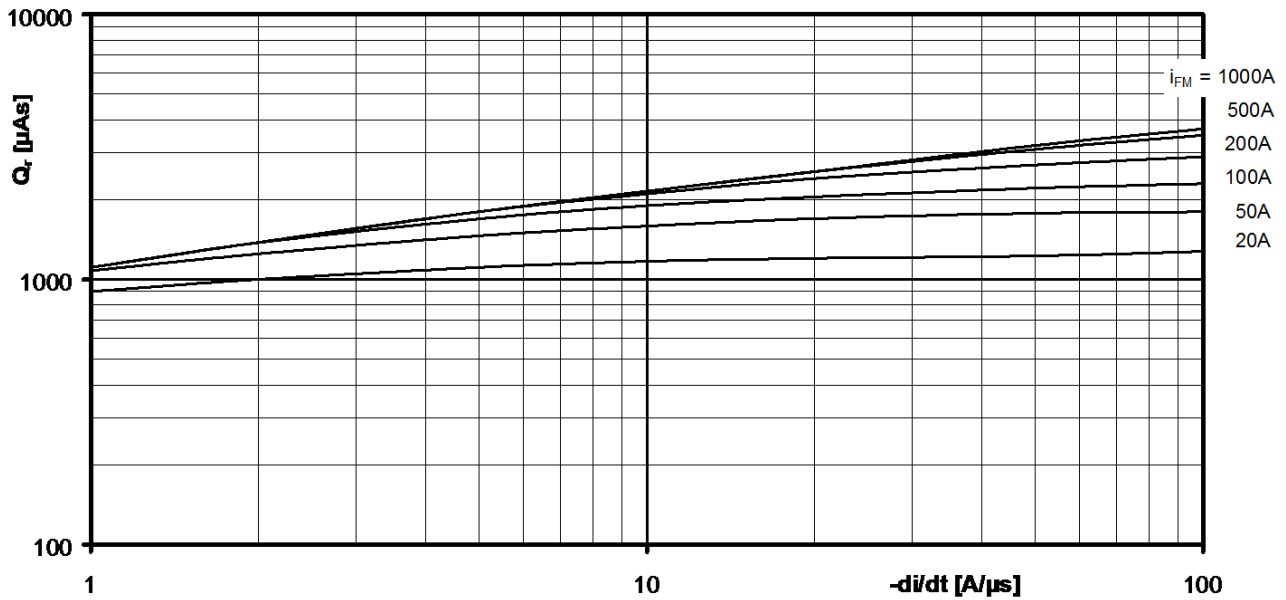
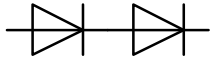
Höchstzulässiger Ausgangsstrom / Maximum rated output current I_D

B6- Sechspuls-Brückenschaltung / Six-pulse bridge circuit

Gesamtverlustleistung der Schaltung / Total power dissipation at circuit P_{tot}

Parameter:

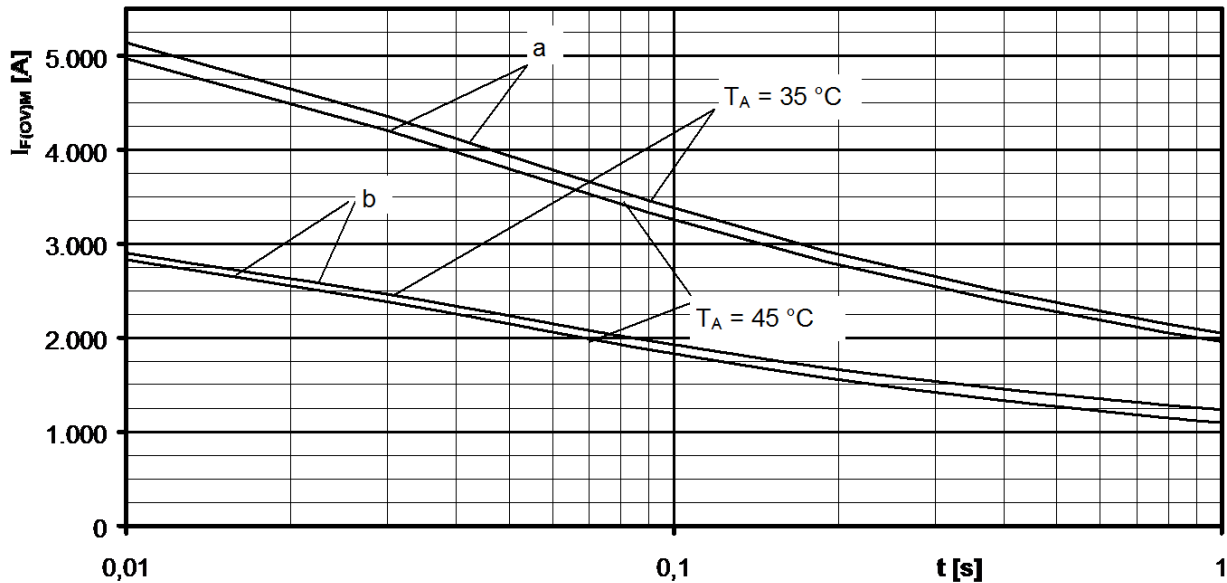
Wärmewiderstand zwischen den Gehäusen und Umgebung / Thermal resistance cases to ambient R_{thCA}



Sperrverzögerungsladung / Recovered charge $Q_r = f(-di/dt)$

$$T_{vj} = T_{vjmax}, V_R \leq 0,5 V_{RRM}, V_{RM} = 0,8 V_{RRM}$$

Parameter: Durchlaßstrom / On-state current i_{FM}



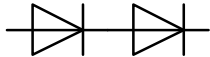
Grenzstrom je Zweig / Maximum overload on-state current per arm $I_{F(OV)M} = f(t), V_{RM} = 0,8 V_{RRM}$

a: Leerlauf / No-load conditions

b: Vorlaststrom je Zweig / Pre-load current per arm $I_{FAV(vor)} = I_{FAVM}$

$T_a = 35^\circ\text{C}$, verstärkte Luftkühlung / Forced air cooling Kühlkörper / Heatsink type: KM17 (Papst 4650)

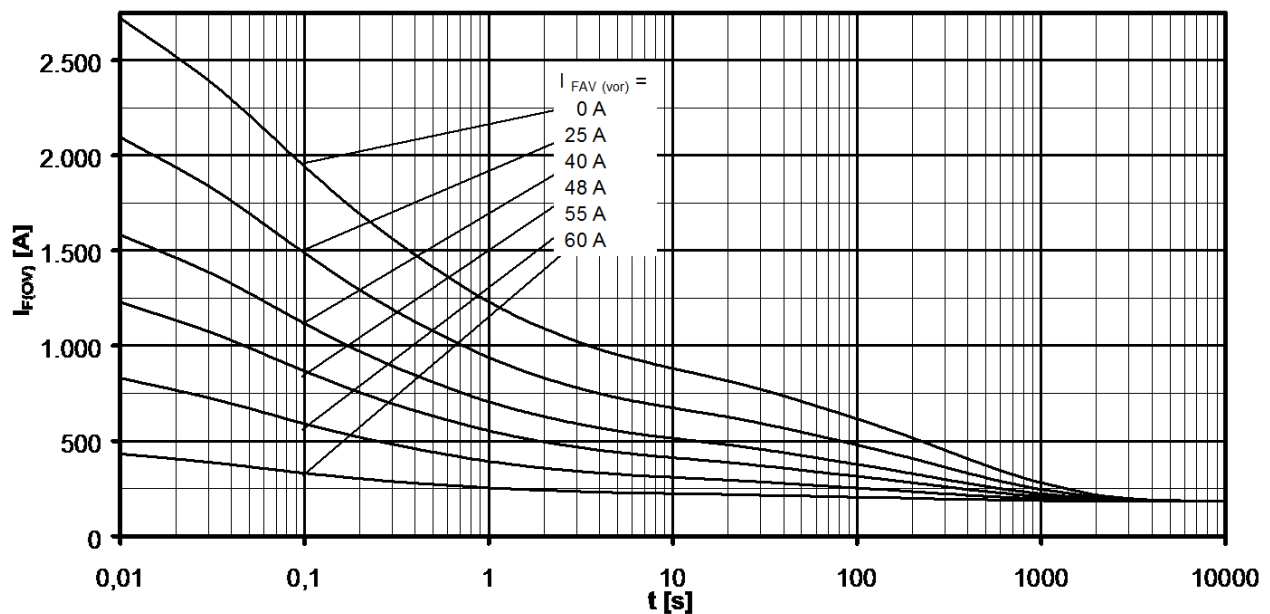
$T_a = 45^\circ\text{C}$, natürliche Luftkühlung / Natural air cooling Kühlkörper / Heatsink type: KM17 (60W)



Netz-Dioden-Modul
Rectifier Diode Module

DD231N

Infineon Technologies Bipolar
GmbH & Co. KG

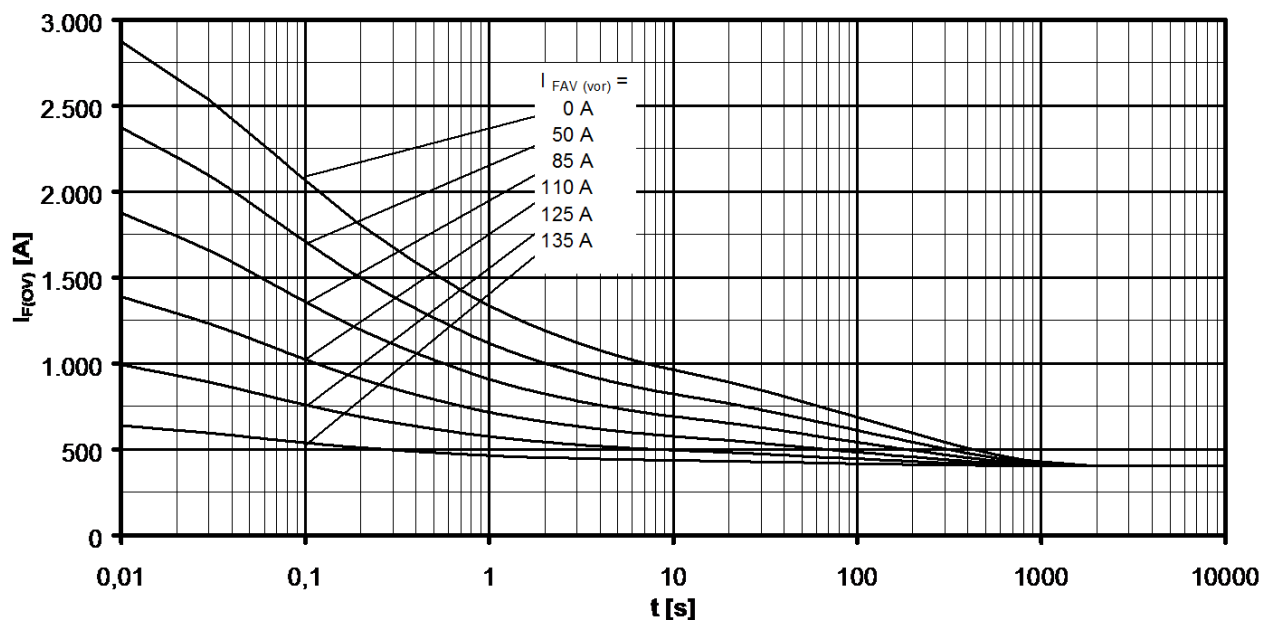


Überstrom je Zweig / Overload on-state current $I_{F(OV)}$

B6- Sechspuls-Brückenschaltung, 120° Rechteck / Six-pulse bridge circuit, 120° rectangular

Kühlkörper / Heatsink type KM17 (60W) Natürliche Kühlung bei / Natural cooling at $T_A = 45^\circ\text{C}$

Parameter: Vorlaststrom je Zweig / Pre-load current per arm $I_{FAV(vor)}$



Überstrom je Zweig / Overload on-state current $I_{F(OV)}$

B6- Sechspuls-Brückenschaltung, 120° Rechteck / Six-pulse bridge circuit 120° rectangular

Kühlkörper / Heatsink type KM17 (Papst 4650) Verstärkte Kühlung bei / Forced cooling at $T_A = 35^\circ\text{C}$

Parameter: Vorlaststrom je Zweig / Pre-load current per arm $I_{FAV(vor)}$